

# 1.5A Dual High-Speed Power MOSFET Drivers

#### **Features**

- High Peak Output Current 1.5A
- · Wide Input Supply Voltage Operating Range:
  - 4.5V to 18V
- High Capacitive Load Drive Capability 1000 pF in 25 nsec (typ.)
- Short Delay Times 40 nsec (typ.)
- · Matched Rise and Fall Times
- · Low Supply Current:
  - With Logic '1' Input 4 mA
  - With Logic '0' Input 400 µA
- Low Output Impedance  $7\Omega$
- Latch-Up Protected: Will Withstand 0.5A Reverse Current
- Input Will Withstand Negative Inputs Up to 5V
- · ESD Protected 4 kV
- Pinouts Same as TC426/TC427/TC428

#### **Applications**

- · Switch Mode Power Supplies
- · Line Drivers
- · Pulse Transformer Drive

#### **General Description**

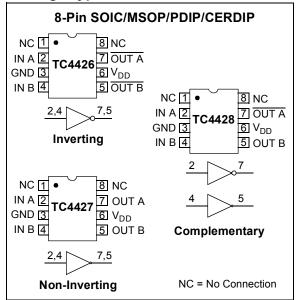
The TC4426/TC4427/TC4428 are improved versions of the earlier TC426/TC427/TC428 family of MOSFET drivers. The TC4426/TC4427/TC4428 devices have matched rise and fall times when charging and discharging the gate of a MOSFET.

These devices are highly latch-up resistant under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking (of either polarity) occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of reverse current (of either polarity) being forced back into their outputs. All terminals are fully protected against electrostatic discharge (ESD) up to 4 kV.

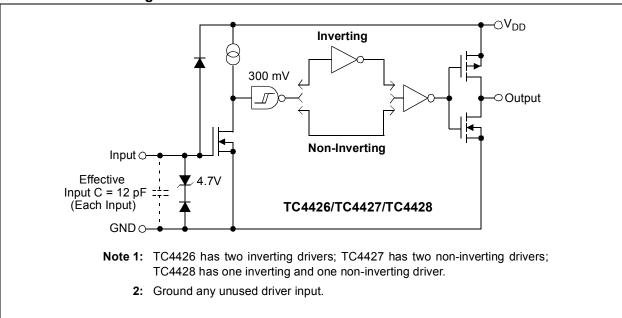
The TC4426/TC4427/TC4428 MOSFET drivers can easily charge/discharge 1000 pF gate capacitances in under 30 nsec and provide low enough impedances in both the 'ON' and 'OFF' states to ensure the MOSFET's intended state will not be affected, even by large transients.

Other compatible drivers are the TC4426A/TC4427A/TC4428A family of devices. The TC4426A/TC4427A/TC4428A devices have matched leading and falling edge input-to-output delay times, in addition to the matched rise and fall times of the TC4426/TC4427/TC4428 devices.

#### **Package Types**



### **Functional Block Diagram**



# 1.0 ELECTRICAL CHARACTERISTICS

### **Absolute Maximum Ratings †**

Supply Voltage+22V
Input Voltage, IN A or IN B
(V <sub>DD</sub> + 0.3V) to (GND – 5V)
Package Power Dissipation (T <sub>A</sub> ≤ 70°C)
PDIP730 mW
CERDIP800 mW
MSOP340 mW
SOIC470 mW
Storage Temperature Range65°C to +150°C
Maximum Junction Temperature+150°C

<sup>†</sup> Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### PIN FUNCTION TABLE

Name	Function					
NC	No Connection					
IN A	Input A					
GND	Ground					
IN B	Input B					
OUT B	Output B					
V <sub>DD</sub>	Supply Input					
OUT A	Output A					
NC	No Connection					

### **DC CHARACTERISTICS**

Electrical Specifications: Unless otherwise noted, $T_A = +25^{\circ}C$ with $4.5V \le V_{DD} \le 18V$ .									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Input									
Logic '1', High Input Voltage	V <sub>IH</sub>	2.4	_	_	V	Note 2			
Logic '0', Low Input Voltage	V <sub>IL</sub>	_	_	0.8	V				
Input Current	I <sub>IN</sub>	-1.0	_	+1.0	μA	$0V \le V_{IN} \le V_{DD}$			
Output									
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> – 0.025	_	_	V	DC Test			
Low Output Voltage	V <sub>OL</sub>	_		0.025	V	DC Test			
Output Resistance	R <sub>O</sub>	_	7	10	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V			
Peak Output Current	I <sub>PK</sub>	_	1.5		Α	V <sub>DD</sub> = 18V			
Latch-Up Protection	I <sub>REV</sub>	_	>0.5	_	Α	Duty cycle ≤ 2%, t ≤ 300 µsec			
Withstand Reverse Current						V <sub>DD</sub> = 18V			
Switching Time (Note 1)									
Rise Time	t <sub>R</sub>	_	19	30	nsec	Figure 4-1			
Fall Time	t <sub>F</sub>	_	25	30	nsec	Figure 4-1			
Delay Time	t <sub>D1</sub>	_	20	30	nsec	Figure 4-1			
Delay Time	t <sub>D2</sub>	_	40	50	nsec	Figure 4-1			
Power Supply									
Power Supply Current	I <sub>S</sub>	_	_	4.5	mA	V <sub>IN</sub> = 3V (Both inputs)			
		_	_	0.4		V <sub>IN</sub> = 0V (Both inputs)			

Note 1: Switching times ensured by design.

2: For V temperature range devices, the V<sub>IH</sub> (Min) limit is 2.0V.

## DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE)

Doromotoro	Hnita	Conditions				
Parameters	Sym	Min	Тур	Max	Units	Conditions
Input						
Logic '1', High Input Voltage	$V_{IH}$	2.4			V	Note 2
Logic '0', Low Input Voltage	$V_{IL}$	_		0.8	V	
Input Current	I <sub>IN</sub>	-10	_	+10	μA	$0V \le V_{IN} \le V_{DD}$
Output						
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> – 0.025	_		V	DC Test
Low Output Voltage	V <sub>OL</sub>	_	_	0.025	V	DC Test
Output Resistance	R <sub>O</sub>	_	9	12	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V
Peak Output Current	I <sub>PK</sub>	_	1.5	_	Α	V <sub>DD</sub> = 18V
Latch-Up Protection	I <sub>REV</sub>		>0.5	_	Α	Duty cycle ≤2%, t ≤300 µsec
Withstand Reverse Current						V <sub>DD</sub> = 18V
Switching Time (Note 1)						
Rise Time	$t_{R}$	_		40	nsec	Figure 4-1
Fall Time	t <sub>F</sub>	_	_	40	nsec	Figure 4-1
Delay Time	t <sub>D1</sub>	_	_	40	nsec	Figure 4-1
Delay Time	t <sub>D2</sub>	_	_	60	nsec	Figure 4-1
Power Supply		•			•	
Power Supply Current	I <sub>S</sub>	_	_	8.0	mA	V <sub>IN</sub> = 3V (Both inputs)
		_	_	0.6		V <sub>IN</sub> = 0V (Both inputs)

Note 1: Switching times ensured by design.

### **TEMPERATURE CHARACTERISTICS**

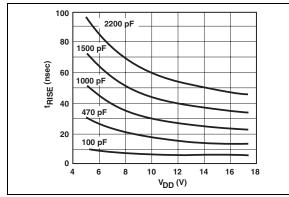
<b>Electrical Specifications:</b> Unless otherwise noted, all parameters apply with 4.5V $\leq$ V <sub>DD</sub> $\leq$ 18V.									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Temperature Ranges									
Specified Temperature Range (C)	T <sub>A</sub>	0		+70	°C				
Specified Temperature Range (E)	T <sub>A</sub>	-40	_	+85	°C				
Specified Temperature Range (V)	T <sub>A</sub>	-40	_	+125	°C				
Specified Temperature Range (M)	T <sub>A</sub>	-55	_	+125	°C				
Maximum Junction Temperature	TJ	_	_	+150	°C				
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C				
Package Thermal Resistances									
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	_	206	_	°C/W				
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	155	_	°C/W				
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	125	_	°C/W				
Thermal Resistance, 8L-CERDIP	$\theta_{JA}$	_	150	_	°C/W				

<sup>2:</sup> For V temperature range devices, the  $V_{IH}$  (Min) limit is 2.0V.

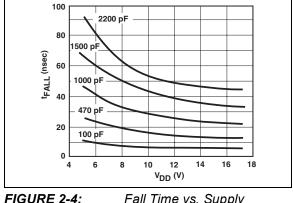
#### 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

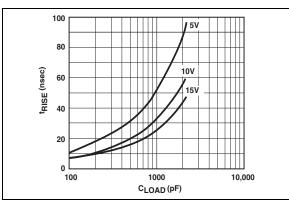
**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with  $4.5V \le V_{DD} \le 18V$ .



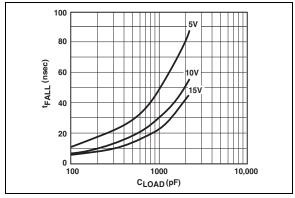
**FIGURE 2-1:** Rise Time vs. Supply Voltage.



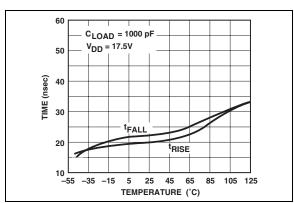
**FIGURE 2-4:** Fall Time vs. Supply Voltage.



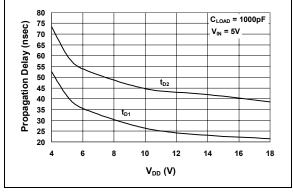
**FIGURE 2-2:** Rise Time vs. Capacitive Load.



**FIGURE 2-5:** Fall Time vs. Capacitive Load.

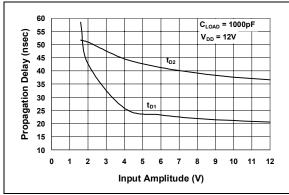


**FIGURE 2-3:** Rise and Fall Times vs. Temperature.



**FIGURE 2-6:** Propagation Delay Time vs. Supply Voltage.

**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with  $4.5V \le V_{DD} \le 18V$ .



**FIGURE 2-7:** Propagation Delay Time vs. Input Amplitude.

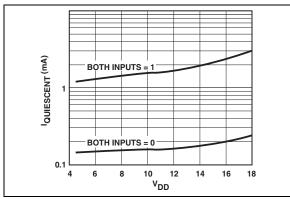
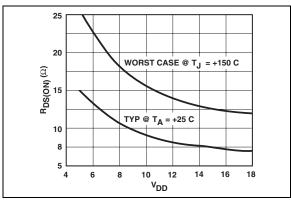
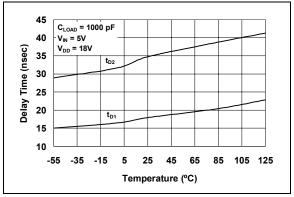


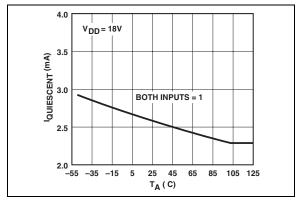
FIGURE 2-8: Supply Current vs. Supply Voltage.



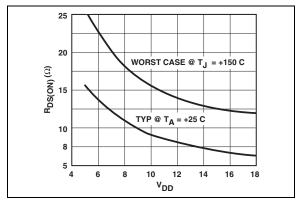
**FIGURE 2-9:** Output Resistance  $(R_{OH})$  vs. Supply Voltage.



**FIGURE 2-10:** Propagation Delay Time vs. Temperature.



**FIGURE 2-11:** Supply Current vs. Temperature.



**FIGURE 2-12:** Output Resistance ( $R_{OL}$ ) vs. Supply Voltage.

**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with  $4.5V \le V_{DD} \le 18V$ .

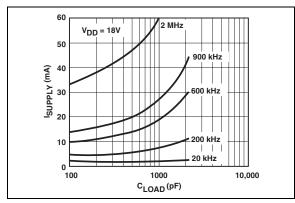


FIGURE 2-13: Supply Current vs. Capacitive Load.

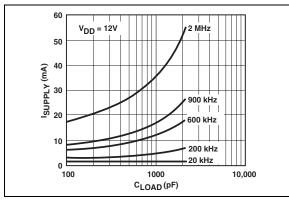
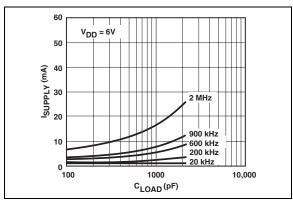
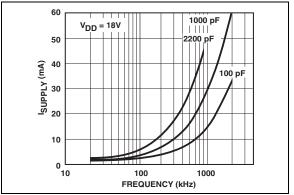


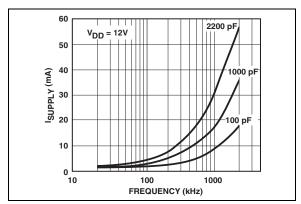
FIGURE 2-14: Supply Current vs. Capacitive Load.



**FIGURE 2-15:** Supply Current vs. Capacitive Load.



**FIGURE 2-16:** Supply Current vs. Frequency.



**FIGURE 2-17:** Supply Current vs. Frequency.

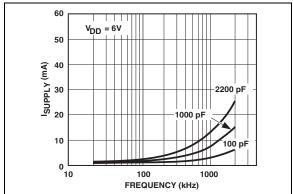
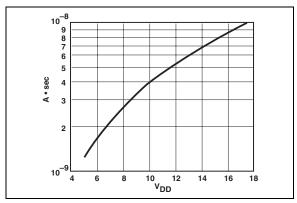


FIGURE 2-18: Supply Current vs. Frequency.

**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with  $4.5V \le V_{DD} \le 18V$ .



**FIGURE 2-19:** Crossover Energy vs. Supply Voltage.

Note: The values seen in this graph represent the loss seen by both drivers in a package during one complete cycle. For a single driver, divide the stated values by 2. For a single transition of a single driver, divide the stated value by 4.

#### 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	Symbol	Description
1	NC	No Connection
2	IN A	Input A
3	GND	Ground
4	IN B	Input B
5	OUT B	Output B
6	$V_{DD}$	Supply Input
7	OUT A	Output A
8	NC	No connection

### 3.1 Inputs A & B

MOSFET driver inputs A & B are high-impedance, TTL/CMOS compatible inputs. These inputs also have 300 mV of hysteresis between the high and low thresholds that prevents output glitching even when the rise and fall time of the input signal is very slow.

#### 3.2 Ground (GND)

Ground.

#### 3.3 Output A & B

MOSFET driver outputs A & B are low-impedance, CMOS push-pull style outputs. The pull-down and pull-up devices are equal strength, making the rise and fall times equivalent.

#### 3.4 Supply Input (V<sub>DD</sub>)

The  $V_{DD}$  input is the bias supply for the MOSFET driver and is rated for 4.5V to 18V with respect to the ground pin. The  $V_{DD}$  input should be bypassed with local ceramic capacitors. The value of these capacitors should be chosen based on the capacitive load that is being driven. A value of 1.0  $\mu F$  is suggested.

### 4.0 APPLICATIONS INFORMATION

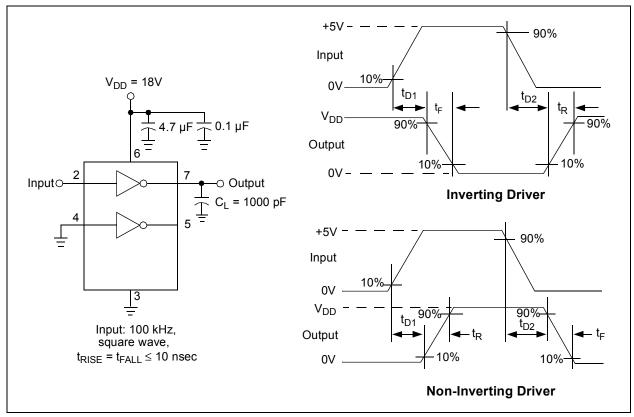
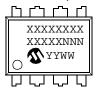


FIGURE 4-1: Switching Time Test Circuit.

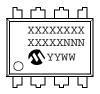
#### 5.0 PACKAGING INFORMATION

### 5.1 Package Marking Information

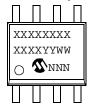




#### 8-Lead CERDIP (300 mil)



#### 8-Lead SOIC (150 mil)



8-Lead MSOP



#### Example:



#### Example:



#### Example:



#### Example:



Legend: XX...X Customer specific information\*

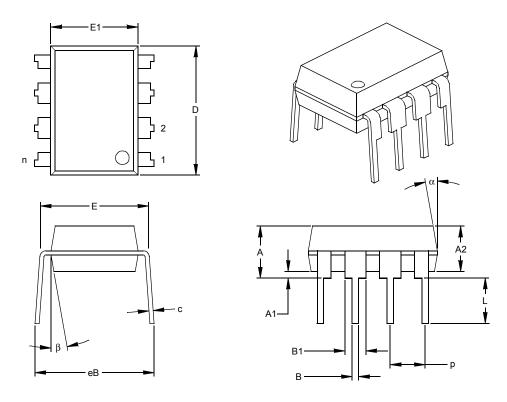
Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

**lote**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

<sup>\*</sup> Standard device marking consists of Microchip part number, year code, week code, and traceability code..

## 8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)



	Units	Units INCHES*			N	IILLIMETERS	;
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

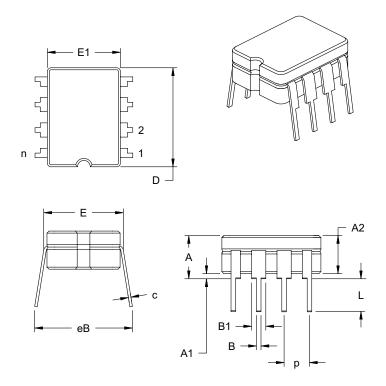
Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001

Drawing No. C04-018

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 8-Lead Ceramic Dual In-line - 300 mil (CERDIP)



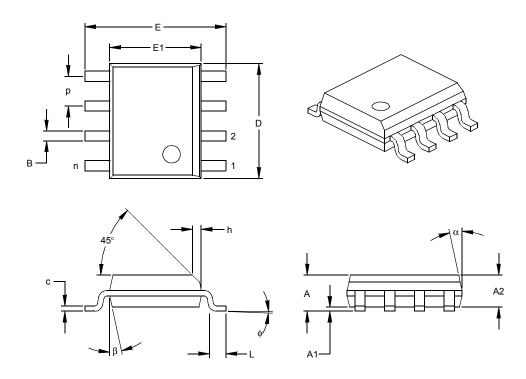
	Units				N	3	
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.160	.180	.200	4.06	4.57	5.08
Standoff §	A1	.020	.030	.040	0.51	0.77	1.02
Shoulder to Shoulder Width	E	.290	.305	.320	7.37	7.75	8.13
Ceramic Pkg. Width	E1	.230	.265	.300	5.84	6.73	7.62
Overall Length	D	.370	.385	.400	9.40	9.78	10.16
Tip to Seating Plane	L	.125	.163	.200	3.18	4.13	5.08
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.055	.065	1.14	1.40	1.65
Lower Lead Width	В	.016	.018	.020	0.41	0.46	0.51
Overall Row Spacing	eВ	.320	.360	.400	8.13	9.15	10.16

<sup>\*</sup>Controlling Parameter

JEDEC Equivalent: MS-030

Drawing No. C04-010

### 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)



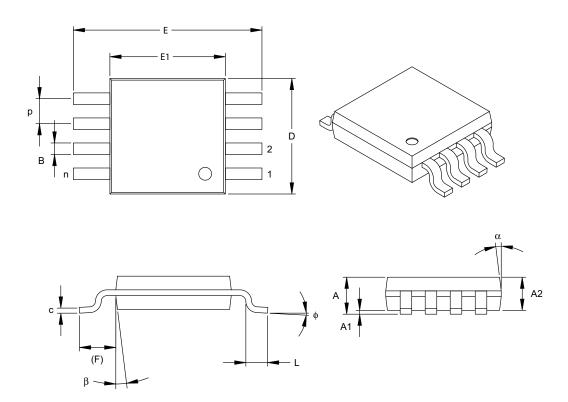
	Units	Units INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

<sup>\*</sup> Controlling Parameter § Significant Characteristic

### 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)



	Units	INCHES			MILLIMETERS*			
Dimension Lim	Dimension Limits			MAX	MIN	NOM	MAX	
Number of Pins	n		8			8		
Pitch	р		.026 BSC			0.65 BSC		
Overall Height	Α	-	-	.043	-	-	1.10	
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95	
Standoff	A1	.000	-	.006	0.00	-	0.15	
Overall Width	E		.193 TYP.			4.90 BSC		
Molded Package Width	E1		.118 BSC		3.00 BSC			
Overall Length	D		.118 BSC		3.00 BSC			
Foot Length	L	.016	.024	.031	0.40	0.60	0.80	
Footprint (Reference)	F		.037 REF		0.95 REF			
Foot Angle	ф	0°	-	8°	0°	-	8°	
Lead Thickness	С	.003	.006	.009	0.08	-	0.23	
Lead Width	В	.009	.012	.016	0.22	-	0.40	
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°	
Mold Draft Angle Bottom	β	5°	ı	15°	5°	-	15°	

<sup>\*</sup>Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

NOTES:

#### PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>x</u>	<u>/<b>XX</b></u>		Exa	mples:	
Device	Temperatur Range	e Package		a)	TC4426COA:	1.5A Dual MOSFET driver, SOIC package, 0°C to +70°C.
Device:	TC4427:	1.5A Dual MOSFET [ 1.5A Dual MOSFET [ 1.5A Dual MOSFET [		b)	TC4426EUA:	1.5A Dual MOSFET driver, MSOP package, -40°C to +85°C.
Temperature Range:	C = E = -	0°C to +70°C (PDIP -40°C to +85°C	and SOIC only)	a)	TC4427CPA:	1.5A Dual MOSFET driver, PDIP package, 0°C to +70°C.
	$V = -40^{\circ}C \text{ to } +125^{\circ}C$	-40°C to +125°C -55°C to +125°C (CEF	RDIP only)	b)	TC4427EPA:	1.5A Dual MOSFET driver, PDIP package, -40°C to +85°C.
Package:	OA = 1 OA713 = 1	Ceramic Dual In-line ( Plastic SOIC, (150 mil Plastic SOIC, (150 mil (Tape and Reel)		a)	TC4428MJA:	1.5A Dual MOSFET driver, CDIP package, -55°C to +125°C.
	UA = Plastic Micro Small Outline (MSOP), 8-lead UA713 = Plastic Micro Small Outline (MSOP), 8-lead (Tape and Reel) PA = Plastic DIP (300 mil Body), 8-lead		utline (MSOP), 8-lead	b)	TC4428COA713:	1.5A Dual MOSFET driver, Tape and Reel, SOIC package, 0°C to +70°C.

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